

SILICON CONTROLLED RECITIFIERS 16 AMP, 400 THRU 600 VOLT



Central Semiconductor Corp.

www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N3669 and 2N3670 are hermetically sealed SCRs designed for sensing circuit applications and control systems. Higher voltage devices and electrical selections are available on special order.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (T_C=25°C unless otherwise noted) SYMBOL UNITS 2N3669 2N3670 Peak Repetitive Off-State Voltage 200 400 VRRM V 600 Peak Repetitive Off-State Voltage 400 V VDRM RMS On-State Current (T_C=90°C) 16 А IT(RMS) Peak One Cycle Surge Current (60Hz, T_C=80°C) 200 А ITSM Peak Gate Current 4.0 IGM А 0.5 Average Gate Power Dissipation W PG(AV) °C Operating and Storage Junction Temperature -40 to +125 TJ, Tstg Thermal Resistance 1.7 °C/W ΘJC ELECTRICAL CHARACTERISTICS: (T_C=25°C unless otherwise noted) SYMBOL TEST CONDITIONS MIN ΤÝΡ MAX UNITS V_R=Rated V_{RRM}, T_C=100°C 1.0 IRRM mΑ VD=Rated VDRM, TC=100°C 2.0 mΑ **I**DRM

lgt	V _D =7.0V	1.0		40	mA
IН	R _G =1.0KΩ	0.5		50	mA
V _{TM}	I _T =25A			1.8	V
V _{GT}	V _D =7.0V			2.0	V
dv/dt	V _D =⅔V _{DRM} , R _G =1.0kΩ, T _C =100°C	10	400		V/µs
t _{gd}	I _G =125mA, diG/dt=1.25A/μs			500	ns
tq	$V_D = V_D = V_D RM$, $V_R = 35V$, $I_T = 10A$, $T_C = 90^{\circ}C$			50	μs

R1 (3-October 2017)



2N3669 2N3670

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А - В _1 - E С ł D — F ŧ G ----H 2 L Κ, \oplus \oplus Μ 4 0 1

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	1.516	1.573	38.50	39.96			
B (DIA)	0.748	0.875	19.00	22.23			
С	0.250	0.450	6.35	11.43			
D	0.433	0.516	11.00	13.10			
Е	0.054	0.065	1.38	1.65			
F	0.048	0.051	1.22	1.30			
G	1.177	1.197	29.90	30.40			
Н	0.650	0.681	16.50	17.30			
J	0.420	0.440	10.67	11.18			
K	0.205	0.225	5.21	5.72			
L (DIA)	0.151	0.172	3.84	4.36			
М	0.984	1.050	25.00	26.67			
TO-3 50 MIL (REV: R0)							

R0

TO-3 50 MIL CASE - MECHANICAL OUTLINE

LEAD CODE: 1) Gate 2) Cathode Case) Anode

MARKING: FULL PART NUMBER

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OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

· Custom product packing

Custom bar coding for shipments

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

REQUESTING PRODUCT PLATING

- If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when 1. ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

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